

L Number	Hits	Search Text	DB	Time stamp
1	33977	channel and FET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:38
2	1411148	channel\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:38
3	86226	field adj effect adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:39
4	5147	channel\$1 near (field adj effect adj transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:40
5	7392	channel\$1 near FET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:40
6	720	channel adj core	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:40
7	171	channel adj envelope	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:41
8	0	(channel adj core) and (channel adj envelope)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:41
9	0	(channel adj core) near FET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:42
10	12	(channel adj core) and FET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:45
11	6	(channel adj envelope) and FET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:45
12	14	(channel adj core) and (field adj effect adj transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:48

13	134	finFET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:48
14	55	fin adj FET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:48
15	114	finFET and channel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:50
16	22	(finFET and channel) and lattice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:52
17	720	first adj lattice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:53
18	629	second adj lattice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:54
19	512	(first adj lattice) and (second adj lattice)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 15:54
20	1	((first adj lattice) and (second adj lattice)) and finFET	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 16:01
21	3	"6635909"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 16:13
22	1756	((first adj lattice) and (second adj lattice)) annd (finFET and channel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 16:13
23	1	((first adj lattice) and (second adj lattice)) and (finFET and channel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 16:20
24	2	"20040121572"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/16 16:20